Single Line CAN/LIN Bus Protector

The NUP1105L has been designed to protect LIN and single line CAN transceivers from ESD and other harmful transient voltage events. This device provides bidirectional protection for the data line with a single SOT-23 package, giving the system designer a low cost option for improving system reliability and meeting stringent EMI requirements.

Features

- SOT-23 Package Allows One Separate Bidirectional Configuration
- 350 W Peak Power Dissipation per Line (8 x 20 µsec Waveform)
- Low Reverse Leakage Current (< 100 nA)
- IEC Compatibility: IEC 61000-4-2 (ESD): Level 4
 - IEC 61000-4-4 (EFT): 40 A 5/50 ns
 - IEC 61000-4-5 (Lighting) 8.0 A (8/20 μs)
- ISO 7637-1, Nonrepetitive EMI Surge Pulse TBD
- ISO 7637–3, Repetitive Electrical Fast Transient (EFT) TBD EMI Surge Pulses
- Flammability Rating UL 94 V-0
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant*

Applications

- Automotive Electronics
 - LIN Bus
 - ◆ Single Line CAN
- Industrial Control Networks
 - ◆ Smart Distribution Systems (SDS®)
 - ◆ DeviceNetTM



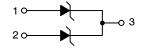
ON Semiconductor®

http://onsemi.com

SOT-23 BIDIRECTIONAL VOLTAGE SUPPRESSOR 350 W PEAK POWER



SOT-23 CASE 318 STYLE 27



PIN 1. ANODE 2. ANODE

3. CATHODE

MARKING DIAGRAM



27H = Device Code
M = Date Code
• = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|---------------------|-------------------------|
| NUP1105LT1G | SOT-23 (Pb-Free) | 3,000 / Tape & Reel |
| SZNUP1105LT1G | SOT-23 (Pb-Free) | 3,000 / Tape & Reel |
| NUP1105LT3G | SOT-23 (Pb-Free) | 10,000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS ($T_J = 25^{\circ}C$, unless otherwise specified)

| Symbol | Rating | Value | Unit |
|--------|---|-----------------|---------------|
| PPK | Peak Power Dissipation 8 x 20 μs Double Exponential Waveform (Note 1) | 350 | W |
| TJ | Operating Junction Temperature Range | -55 to 150 | °C |
| TJ | Storage Temperature Range | -55 to 150 | °C |
| TL | Lead Solder Temperature (10 s) | 260 | °C |
| ESD | Human Body model (HBM) Machine Model (MM) IEC 61000-4-2 Specification (Contact) | 16 400 30 | kV V kV |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

| Symbol | Parameter | Test Conditions | Min | Тур | Max | Unit |
|------------------|----------------------------|--|------|-----|----------|------|
| V _{RWM} | Reverse Working Voltage | (Note 2) | 24 | | | V |
| V _{BR} | Breakdown Voltage | I _T = 1 mA (Note 3) | 25.7 | | 28.4 | V |
| I _R | Reverse Leakage Current | V _{RWM} = 24 V | | 15 | 100 | nA |
| V _C | Clamping Voltage | I _{PP} = 5 A (8 x 20 μs Waveform) (Note 4) | | | 40 | V |
| V _C | Clamping Voltage | I _{PP} = 8 A (8 x 20 μs Waveform) (Note 4) | | | 44 | V |
| I _{PP} | Maximum Peak Pulse Current | 8 x 20 μs Waveform (Note 4) | | | 8.0 | Α |
| CJ | Capacitance | $V_R = 0$ V, f = 1 MHz (Anode to GND) $V_R = 0$ V, f = 1 MHz (Anode to Anode) | | | 60 30 | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Pulse waveform per Figure 1.
 Include SZ-prefix devices where applicable.

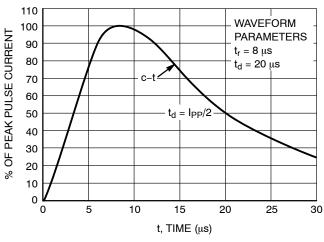
^{1.} Non-repetitive current pulse per Figure 1.

^{2.} TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.

3. V_{BR} is measured at pulse test current I_T.

TYPICAL PERFORMANCE CURVES

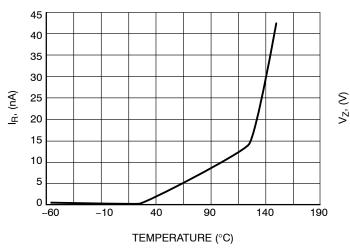
 $(T_J = 25^{\circ}C \text{ unless otherwise noted})$



12.0 € PULSE WAVEFORM IPP, PEAK PULSE CURRENT 8 x 20 μs per Figure 1 10.0 8.0 6.0 4.0 2.0 0.0 30 35 40 25 45 50 V_C, CLAMPING VOLTAGE (V)

Figure 1. Pulse Waveform, 8 \times 20 μs

Figure 2. Clamping Voltage vs Peak Pulse Current



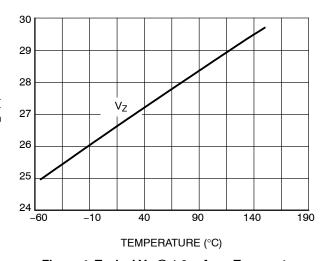


Figure 3. Typical Leakage vs. Temperature

Figure 4. Typical $V_Z @ 1.0 \ \text{mA} \ \text{vs.}$ Temperature

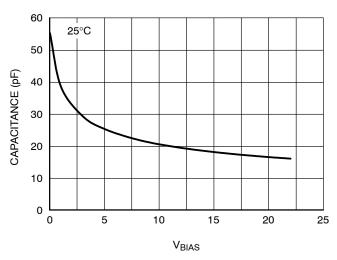


Figure 5. Capacitance vs. V_{BIAS}

APPLICATIONS SECTION

The NUP1105L provides a transient voltage suppression solution for the LIN data communication bus. The NUP1105L is a dual bidirectional TVS device in a compact SOT-23 package. This device is based on Zener technology that optimizes the active area of a PN junction to provide robust protection against transient EMI surge voltage and ESD. The NUP1105L has been tested to EMI and ESD levels that exceed the specifications of popular high speed LIN networks.

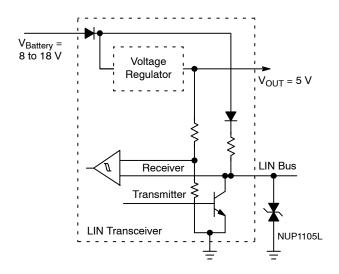


Figure 6. LIN Transceiver

The NUP1105L device can be used to provide transcient voltage suppression for a single data line CAN system. Figure 7 provides an example of a single data line CAN protection circuit.

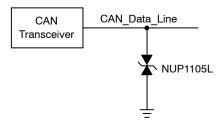
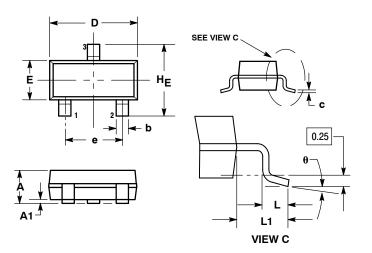


Figure 7. High-Speed and Fault Tolerant CAN TVS
Protection Circuit

PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



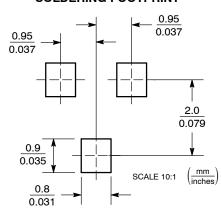
NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|--------|-------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.040 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.001 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.018 | 0.020 |
| С | 0.09 | 0.13 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| е | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.081 |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.029 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| θ | 0° | | 10° | 0° | | 10° |

- STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE

SOLDERING FOOTPRINT



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